



## 2SA2016/2SC5569

### DC/DC Converter Applications

#### Applications

- Relay drivers, lamp drivers, motor drivers, strobes.

#### Features

- Adoption of FBET and MBIT processes.
- High current capacitance.
- Low collector-to-emitter saturation voltage.
- High-speed switching.
- Ultrasmall package facilitates miniaturization in end products.
- High allowable power dissipation.

#### Specifications

( ) : 2SA2016

#### Absolute Maximum Ratings at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	$V_{CBO}$		(-50)80	V
Collector-to-Emitter Voltage	$V_{CEO}$		(-50)	V
Emitter-to-Base Voltage	$V_{EBO}$		(-6)	V
Collector Current	$I_C$		(-7)	A
Collector Current (Pulse)	$I_{CP}$		(-10)	A
Base Current	$I_B$		(-1.2)	A
Collector Dissipation	$P_C$	Mounted on a ceramic board (250mm <sup>2</sup> ×0.8mm)	1.3	W
		$T_c=25^\circ\text{C}$	3.5	W
Junction Temperature	$T_J$		150	$^\circ\text{C}$
Storage Temperature	$T_{stg}$		-55 to +150	$^\circ\text{C}$

#### Electrical Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	$I_{CBO}$	$V_{CB}=(-)40\text{V}, I_E=0$			(-0.1)	$\mu\text{A}$
Emitter Cutoff Current	$I_{EBO}$	$V_{EB}=(-)4\text{V}, I_C=0$			(-0.1)	$\mu\text{A}$
DC Current Gain	$h_{FE}$	$V_{CE}=(-)2\text{V}, I_C=(-)500\text{mA}$	200		560	
Gain-Bandwidth Product	$f_T$	$V_{CE}=(-)10\text{V}, I_C=(-)500\text{mA}$		(290)		MHz
				330		MHz
Output Capacitance	$C_{ob}$	$V_{CB}=(-)10\text{V}, f=1\text{MHz}$		(50)28		pF

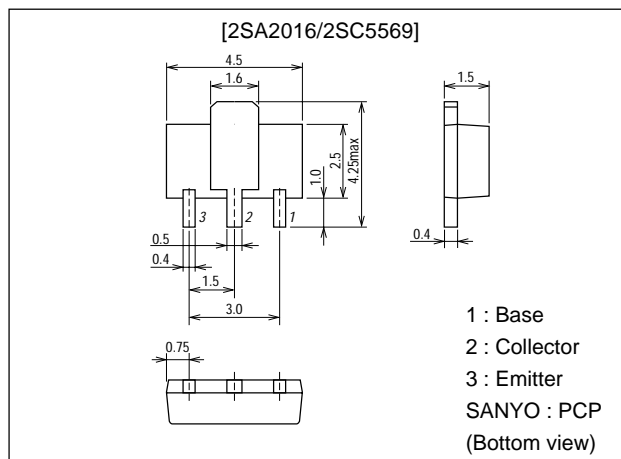
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#### Package Dimensions

unit:mm

2163



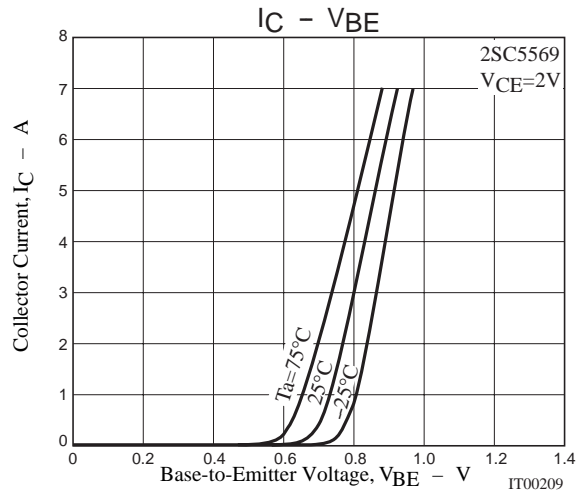
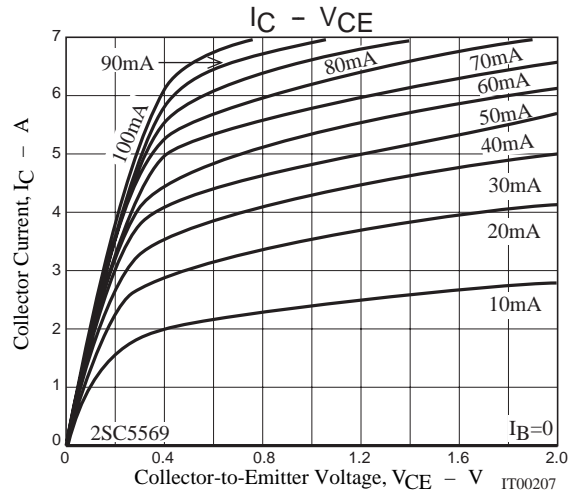
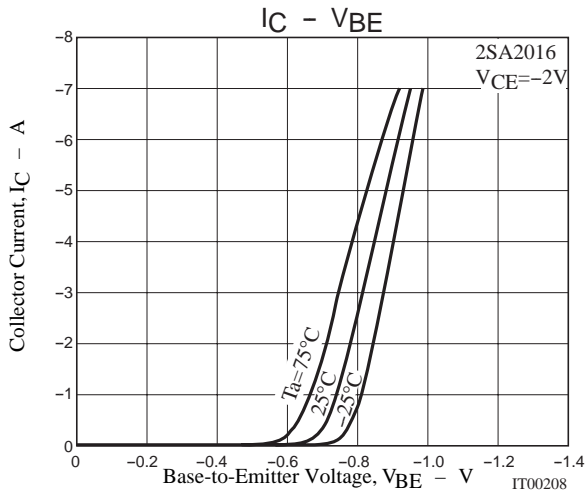
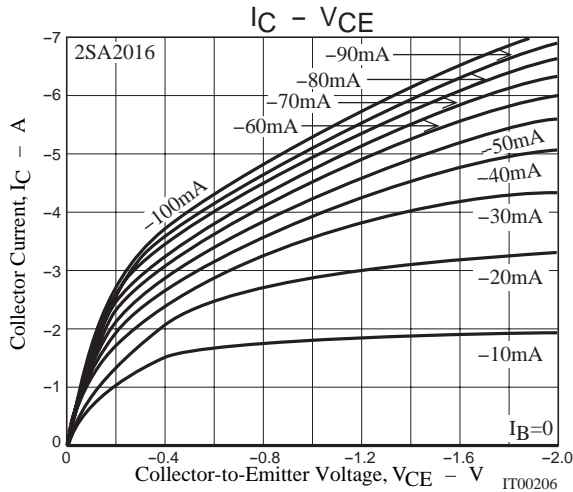
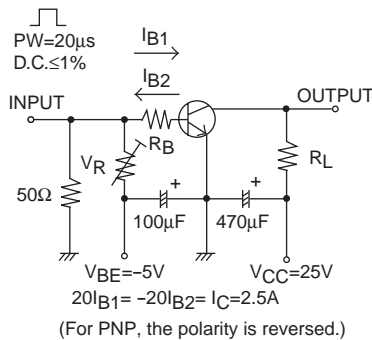
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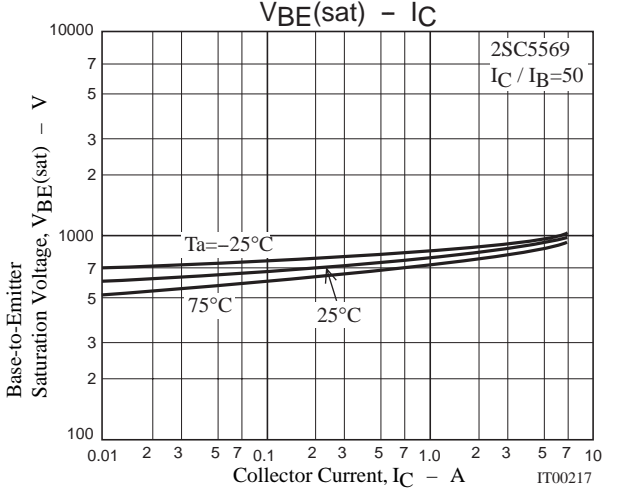
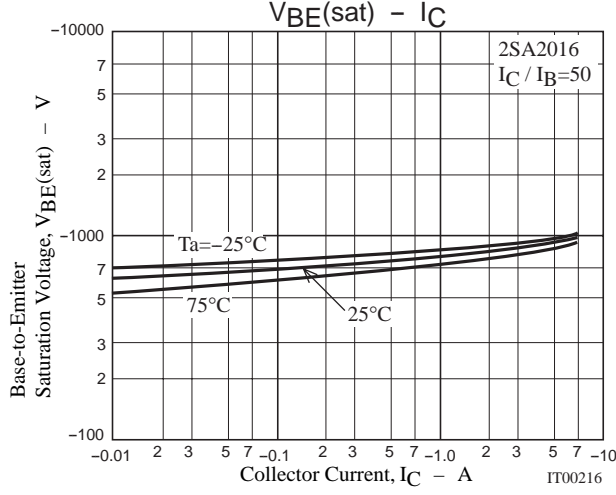
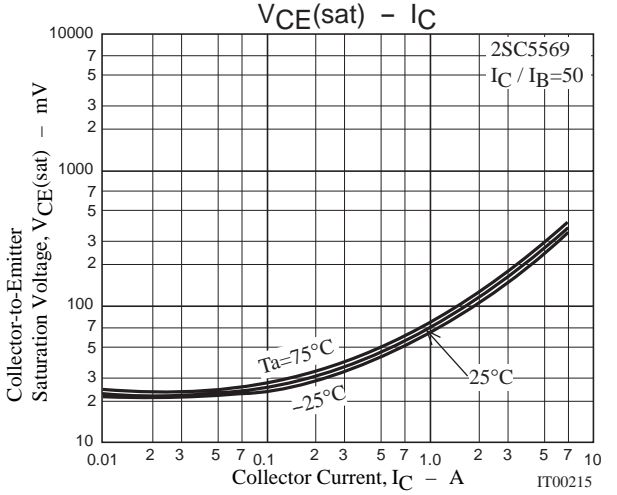
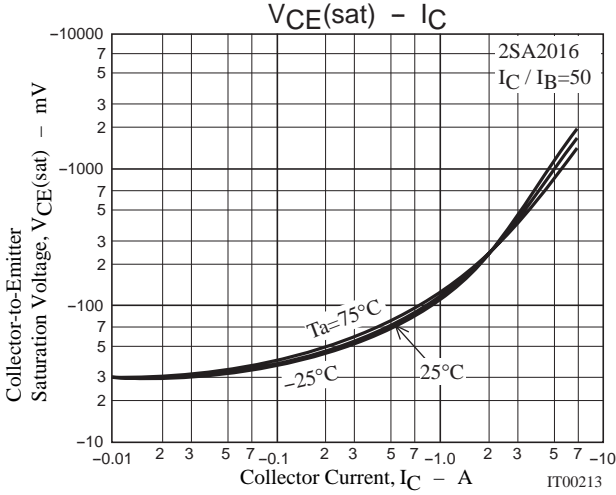
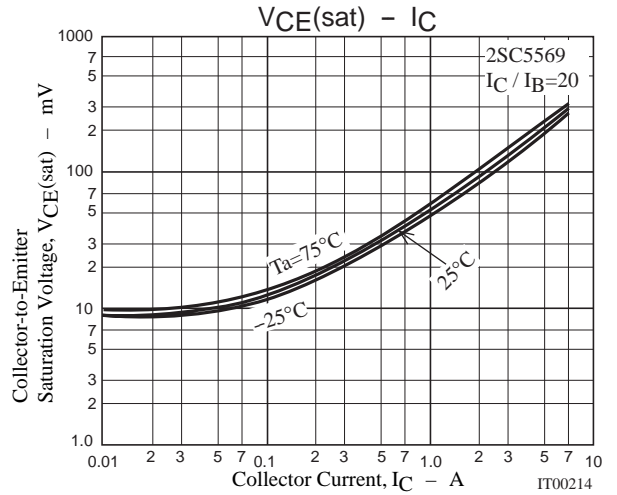
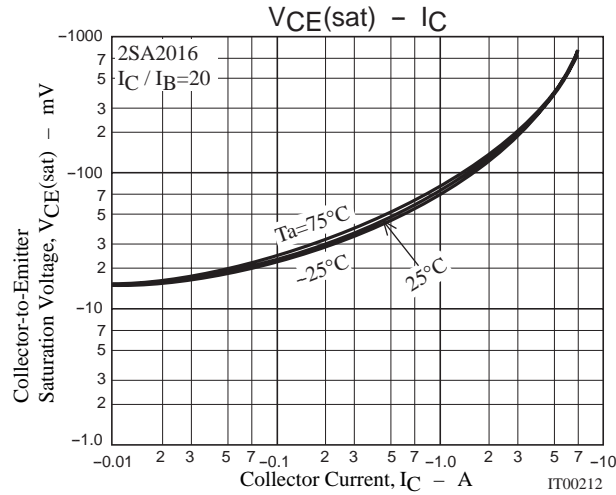
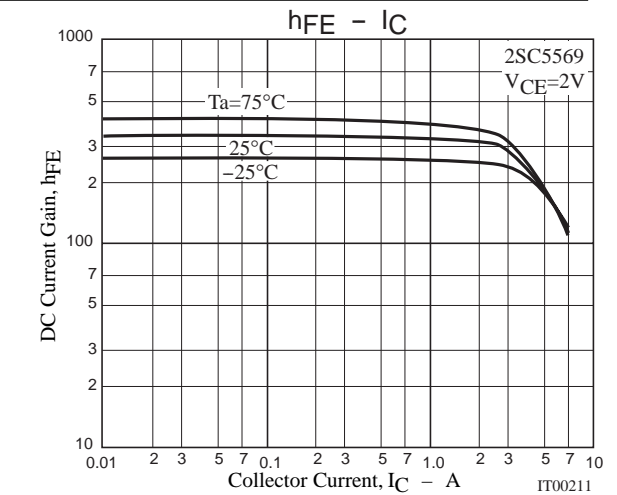
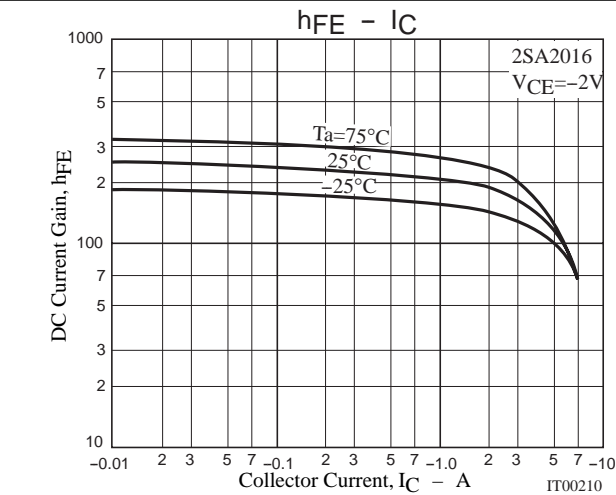
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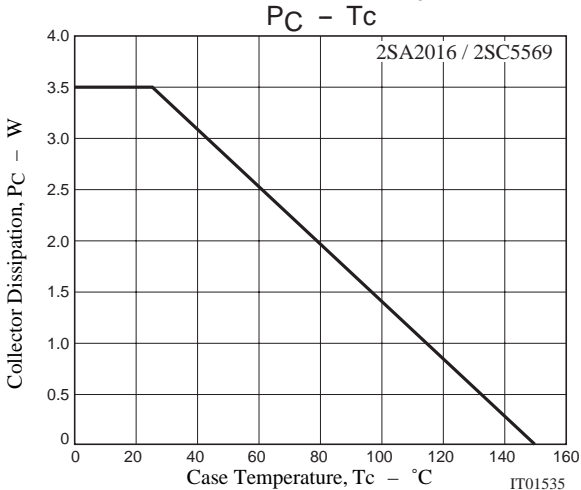
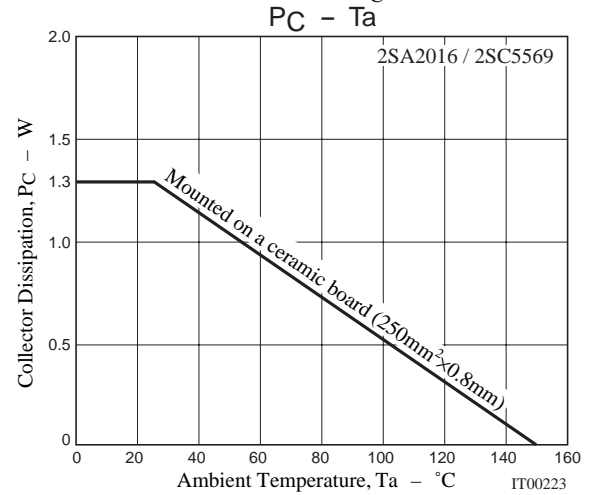
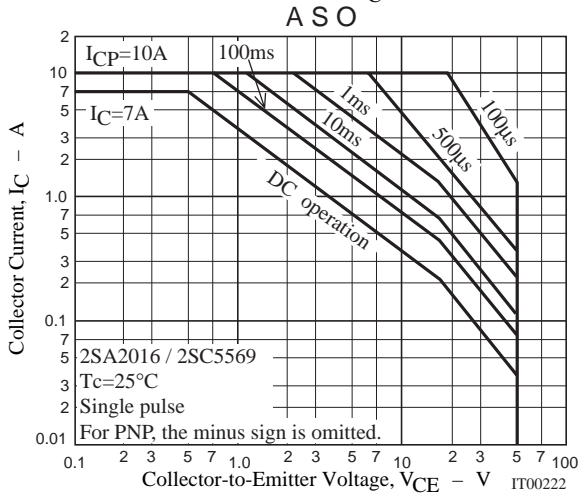
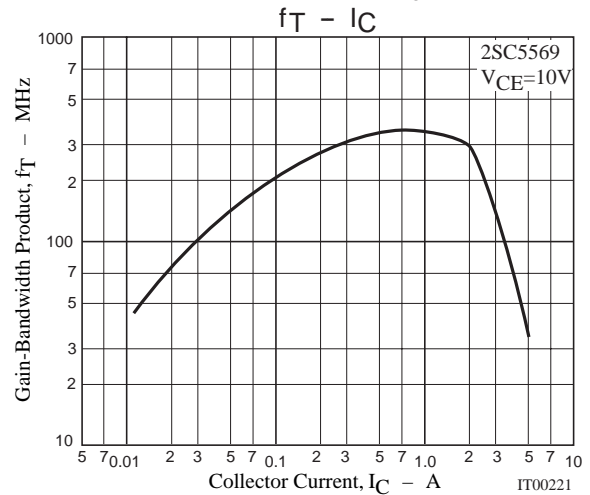
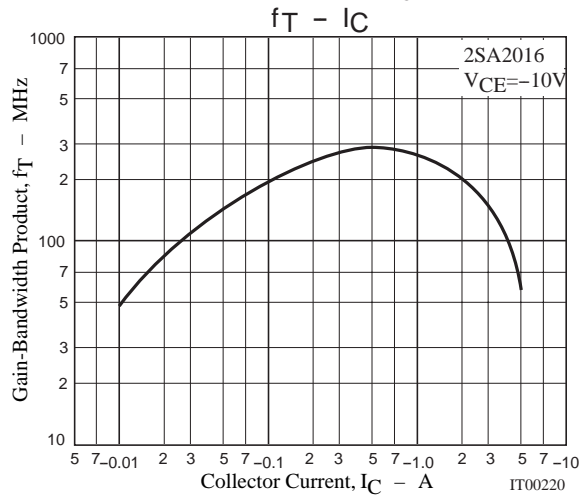
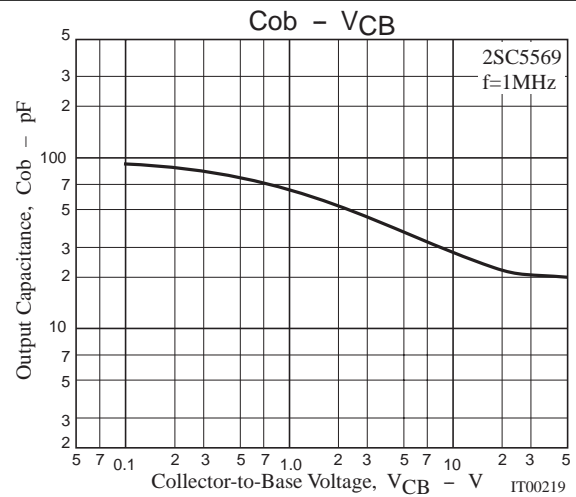
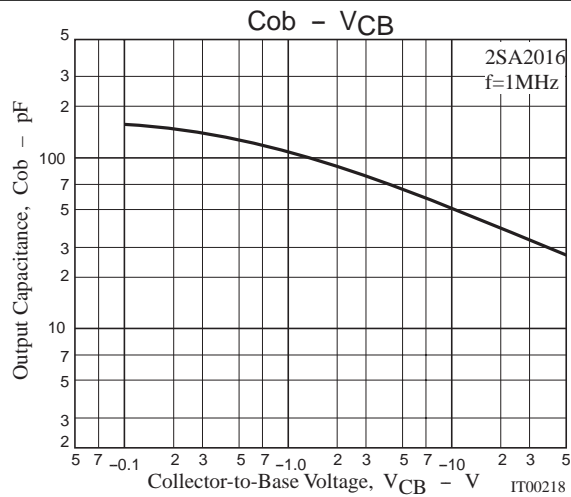
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=(-)3.5A, I_B=(-)175mA$		(-230)	(-390)	mV
				160	240	mV
		$I_C=(-)2A, I_B=(-)40mA$		(-240)	(-400)	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=(-)2A, I_B=(-)40mA$		(-0.83)	(-1.2)	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=(-)10\mu A, I_E=0$	(-50)			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=(-)1mA, R_{BE}=\infty$	(-50)			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=(-)10\mu A, I_C=0$	(-6)			V
Turn-ON Time	$t_{on}$	See specified Test Circuit		(40)30		ns
Storage Time	$t_{stg}$	See specified Test Circuit		(225)		ns
Fall Time	$t_f$	See specified Test Circuit		420		ns
				25		ns

Switching Time Test Circuit







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